TECHNICAL DATA DATA SHEET 255, REV. C

# HERMETIC POWER SCHOTTKY RECTIFIER 200°C Maximum Operation Temperature

#### **MAXIMUM RATINGS**

ALL RATINGS ARE @ T<sub>C</sub> = 25 °C UNLESS OTHERWISE SPECIFIED.

| <u> </u>   | 2                |                |       |
|--|------------------|----------------|-------|
| RATING   | SYMBOL           | MAX.           | UNITS |
| PEAK INVERSE VOLTAGE   | PIV              | 100            | Volts |
| MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ T <sub>C</sub> =100 °C) | Io               | 60             | Amps  |
| MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t=10ms, Sine)                   | I <sub>FSM</sub> | 700            | Amps  |
| MAXIMUM JUNCTION CAPACITANCE (V <sub>r</sub> =5V)                            | C <sub>T</sub>   | 1500           | pF    |
| MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)           | $R\theta_{JC}$   | 0.35           | °C/W  |
| MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE                              | Top/Tstg         | -65 to<br>+200 | °C    |

#### **ELECTRICAL CHARACTERISTICS**

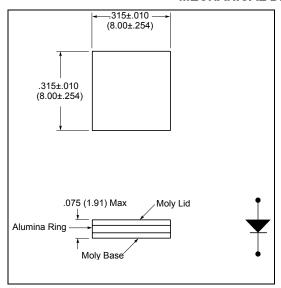
| CHARACTERISTIC   |                |      |       |
|--|----------------|------|-------|
| MAXIMUM FORWARD VOLTAGE DROP, Pulsed (per leg, I <sub>f</sub> = 60 Amps) |                |      |       |
| T <sub>J</sub> = 25 °C   | $V_{f}$        | 0.87 | Volts |
| T <sub>J</sub> = 125 °C  |                | 0.72 |       |
| MAXIMUM REVERSE CURRENT (per leg, I <sub>r</sub> @ 100 V PIV)            |                |      |       |
| T <sub>J</sub> = 25 °C   | I <sub>r</sub> | 0.5  | mA    |
| T <sub>J</sub> = 125 °C  |                | 3.0  |       |

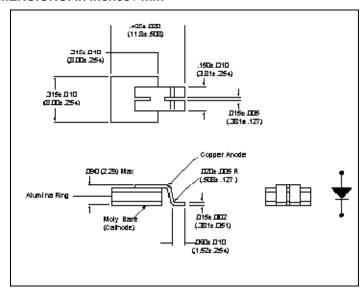
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### **MECHANICAL DIMENSIONS: In Inches / mm**





SHD-2

# SHD-2B



